

PARA LIGHT ELECTRONICS CO., LTD.

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DATA SHEET

PART NO.: PA-ITRLT8102

REV: <u>A/0</u>

CUSTOMER'S APPROVAL : _____ DCC : ____



PA-ITRLT8102

REV:A/0

Descriptions

The PA-ITRLT8102 consist of an infrared emitting diode and an NPN siliconphototransistor, encased side-by-side on converging optical axis in a blackthermoplastic housing The phototransistor receives radiation from the IR only . This is the normal situation. But when an object is in between ,phototran sistor could not receives the radiation.

Features

Fast response time

High analytic

Cut-off visible wavelength λp=940nm

High sensitivity

Pb free

This product itself will remain within RoHS compliant version

Applications

Printers

Switch Scanner

Floppy disk driver

Non-contact Switching

For Direct Board

Device Selection Guide

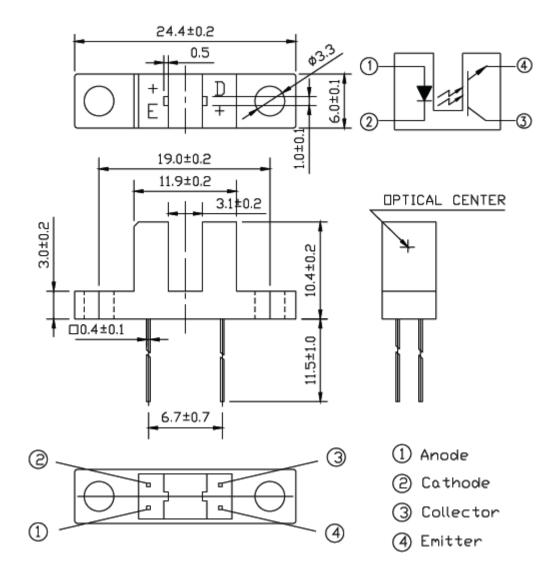
Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Water clear
PT	Silicon	Water clear



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Package Dimension



Note:

- 1.All dimensions are in millimeters.
- 2. Tolerances unless dimensions ±0.3mm.
- 3.Lead spacing is measured where the lead emerge from the package



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Absolute Maximum Ratings

	Parameter	Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V_R	5	V
	Forward Current	I_{F}	50	mA
	Peak Forward Current (*1) Pulse width ≤ 100 μ s, Duty cycle=1%	I_{FP}	1	A
Output	Collector Power Dissipation	P_{C}	75	mW
	Collector Current	$I_{\mathbf{C}}$	30	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	v
Operating	Temperature	Topr	-25~+85	°C
Storage To	emperature	Tstg	-40~+85	$^{\circ}\!\mathbb{C}$
	ering Temperature (*2) form body for 5 seconds)	Tsol 260		°C

^(* 1) tw=100 µsec. , T=10 msec. (* 2) t=5 Sec

Electro-Optical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input	Forward Voltage	V _F		1.2	1.5	V	I _F =20mA	
	Reverse Current	I_R			10	$\mu \mathbf{A}$	V _R =5V	
	Peak Wavelength	λp		940		nm	I _F =20mA	
	View Angle	201/2		60		Deg	I _F =20mA	
Output	Dark Current	I _{CEO}			100	nA	$V_{CE}=20V,Ee=0mW/cm^2$	
	C-E Saturation Voltage	V _{CE} (sat)			0.4	v	$I_C=2mA$ Ee=1mW/cm ²	
Transfer Characteristics	Collect Current	I _C (ON)	0.9		15	mA	V _{CE} =5V I _F =20mA	
	Rise time	t _r		15		μ sec	V _{CE} =5V	
	Fall time	t _f		15		μ sec	$I_C=1mA$ $R_L=1K\Omega$	



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Typical Electrical/Optical/Characteristics Curves for IR

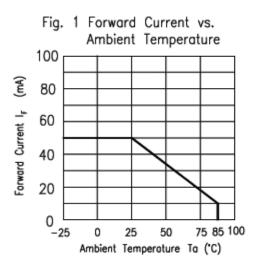


Fig. 3 Peak Emission Wavelength vs. Ambient Temperature

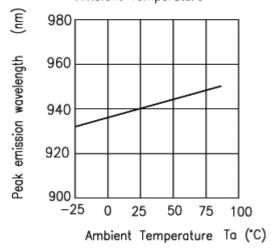


Fig. 5 Forward Voltage vs. Ambient Temperature

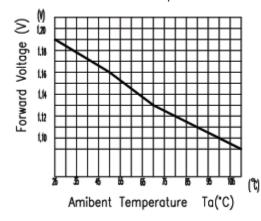


Fig. 2 Spectral Distribution ি 100 I_s =20m Ta=25°C Relative radiant intensity 80 60 40

Fig. 4 Forward Current vs. Forward Voltage

Wavelength λ (nm)

20

0

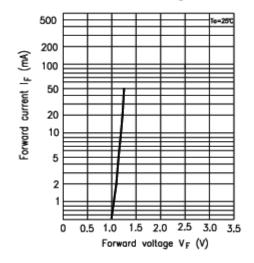
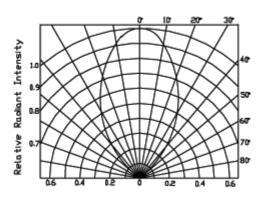


Fig. 6 Relative Radiant Intensity vs. Angular Displacement





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Typical Electrical/Optical/Characteristics Curves for PT

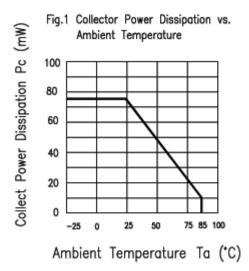


Fig. 3 Relative Collector Current vs. Ambient Temperature

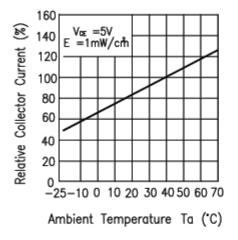


Fig.5 Spectral Sensitivity

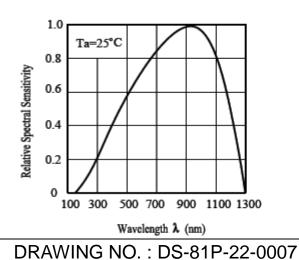


Fig.2 Collector Dark Current vs. Ambient Temperature

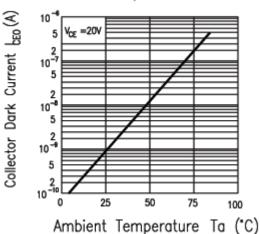


Fig.4 Collector Current vs. Irradiance

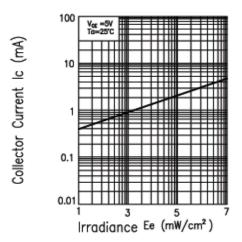
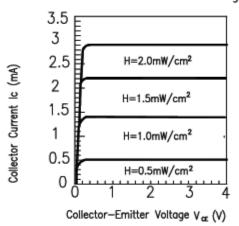


Fig.6 Collector Current vs. Collector—Emitter Voltag



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Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditio	Test on Hours	s/ Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5	5 °C 10sec	22 pcs		0/1
2	Temperature Cycle	5:	min 300 cycle	22 nes	$I_R \ge U \times 2$ $Ee \le L \times 0.8$ $V_F \ge U \times 1.2$	0/1
3	Thermal Shock	10 s	sec 300 cycle	22 pcs	U :Upper specification limit L :Lower specification limit	0/1
4	High Temperature Storage	TEMP. : +100℃	1000 h	rs 22 pcs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000 h	ers 22 pcs		0/1
6	DC Operating Life	V _{CE} =5V I _F =20mA	1000 h	ars 22 pcs		0/1
7	High Temperature / High Humidity	85℃ / 85% R.H.	1000 h	ers 22 pcs		0/1



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Notes

- 1. Above specification may be changed without notice. WE will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instruction for using outlined in these specification sheets. Para light assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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